







CD54HC273, CD74HC273 CD54HCT273, CD74HCT273

SCHS174C - FEBRUARY 1998 - REVISED JANUARY 2022

CDx4HC(T)273 High-Speed CMOS Logic Octal D-Type Flip-Flop with Reset

1 Features

- Common clock and asynchronous controller reset
- Positive edge triggering
- **Buffered** inputs
- Fanout (over temperature range)
 - Standard outputs: 10 LSTTL loads
 - Bus driver outputs: 15 LSTTL loads
- Wide operating temperature range: -55°C to 125°C
- Balanced propagation delay and transition times
- Significant power reduction compared to LSTTL Logic ICs
- · HC types:
 - 2 V to 6 V operation
 - High noise immunity: $N_{IL} = 30\%$, $N_{IH} = 30\%$ of V_{CC} at $V_{CC} = 5V$
- HCT types:
 - 4.5 V to 5.5 V operation
 - Direct LSTTL input logic compatibility, V_{IL} = 0.8 $V (max), V_{IH} = 2 V (min)$
 - CMOS input compatibility, I_I ≤ 1 μA at V_{OI} ,V_{OH}

2 Description

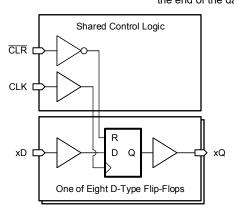
The 'HC273 and 'HCT273 high speed octal D-Type flip-flops with a direct clear input are manufactured with silicon-gate CMOS technology. They possess the low power consumption of standard CMOS integrated circuits.

Information at the D input is transferred to the Q outputs on the positive-going edge of the clock pulse. All eight flip-flops are controlled by a common clock (CLK) and a common reset (CLR). Resetting is accomplished by a low voltage level independent of the clock. All eight Q outputs are reset to a logic 0.

Device Information

PART NUMBER	PACKAGE ⁽¹⁾	BODY SIZE (NOM)				
CD54HC273F	CDIP (20)	26.92 mm × 6.92 mm				
CD74HC273M	SOIC (20)	12.80 mm × 7.50 mm				
CD74HC273E	PDIP (20)	25.40 mm × 6.35 mm				
CD74HCT273M	SOIC (20)	12.80 mm × 7.50 mm				
CD74HCT273	PDIP (20)	25.40 mm × 6.35 mm				

For all available packages, see the orderable addendum at (1) the end of the data sheet.



Functional Block Diagram



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3 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision B (May 2003) to Revision C (January 2022)

Page

- Updated the numbering, formatting, tables, figures, and cross-refrences throughout the document to reflect modern data sheet standards......



4 Pin Configuration and Functions

CLR	1 🔿	20	□□ V _{cc}
1Q <u> </u>	2	19	□□ 8Q
1D 🖵	3	18	□□ 8D
2D □□□	4	17	□□ 7D
2Q 🗀	5	16	7Q
3Q 🗀	6	15	□□ 6Q
3D □□□	7	14	□□ 6D
4Q <u></u>	8	13	□□ 5D
4D □□□	9	12	□□ 5Q
GND □□□	10	11	□□ CLK

J, DW or N package 20-Pin CDIP, PDIP or SOIC Top View



5 Specifications

5.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)⁽¹⁾

			MIN	MAX	UNIT
V _{CC}	Supply voltage		- 0.5	7	V
I _{IK}	Input clamp diode current	For $V_1 < -0.5 \text{ V}$ or $V_1 > V_{CC} + 0.5 \text{ V}$		±20	mA
I _{OK}	Output clamp diode current	For $V_O < -0.5 \text{ V}$ or $V_O > V_{CC} + 0.5 \text{ V}$		±20	mA
Io	Drain current, per output	For -0.5 V < V _O < V _{CC} + 0.5 V		±25	mA
Io	Output source or sink current per output pin	For $V_O > -0.5 \text{ V}$ or $V_O < V_{CC} + 0.5 \text{ V}$		±25	mA
	Continuous current through V _{CC} or ground curr	rent		±50	mA
TJ	Junction temperature			150	°C
T _{stg}	Storage temperature range	– 65	150	°C	
	Lead temperature (Soldering 10s) (SOIC - Lea	d Tips Only)		300	°C

⁽¹⁾ Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

5.2 Recommended Operating Conditions

			MIN	MAX	UNIT	
T _A	Temperature range		-55	125	°C	
V _{CC}	Cumply voltage range	HC types	2	6	~	
	Supply voltage range	HCT types	4.5	5.5	V	
V _I , V _O	DC input or output voltage	·	0	V _{CC}	V	
		2 V		1000		
t _t	Input rise and fall time	4.5 V		500	ns	
		6 V		400		

5.3 Thermal Information

		DW (SOIC)	N (PDIP)	
THERMAL METRI	С	20 PINS	20 PINS	UNIT
$R_{\theta JA}$	Junction-to-ambient thermal resistance ⁽¹⁾	58	69	°C/W

⁽¹⁾ For more information about traditional and new thermal metrics, see the Semiconductor and IC package thermal metrics application report.



5.4 Electrical Characteristics

	DADAMETER	TEST	V- 00		25℃		–40℃ to	85℃	–55℃ to 125℃		UNIT	
	PARAMETER	CONDITIONS ⁽²⁾	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNII	
HC TY	PES							'		'		
			2	1.5			1.5		1.5			
√ _{IH}	High level input voltage		4.5	3.15			3.15		3.15		V	
	vollago		6	4.2			4.2		4.2			
			2			0.5		0.5		0.5		
√ _{IL}	Low level input voltage		4.5			1.35		1.35		1.35	V	
	romago		6			1.8		1.8		1.8		
	High level output	I _{OH} = – 20 μA	2	1.9			1.9		1.9			
	voltage	I _{OH} = – 20 μA	4.5	4.4			4.4		4.4		V	
/ _{OH}	CMOS loads	I _{OH} = – 20 μA	6	5.9			5.9		5.9			
OH	High level output	I _{OH} = – 4 mA	4.5	3.98			3.84		3.7			
	voltage TTL loads	I _{OH} = - 5.2 mA	6	5.48			5.34		5.2		V	
	Low level output	I _{OL} = 20 μA	2			0.1		0.1		0.1		
	voltage	I _{OL} = 20 μA	4.5			0.1	-	0.1	-	0.1	V	
,	CMOS loads	I _{OL} = 20 μA	6			0.1		0.1		0.1		
_{OL}	Low level output	I _{OL} = 4 mA	4.5			0.26		0.33		0.4		
	voltage TTL loads	I _{OL} = 5.2 mA	6			0.26		0.33		0.4	V	
l	Input leakage current	V _I = V _{CC} or GND	6			±0.1		±1		±1	m <i>A</i>	
СС	Quiescent device current	V _I = V _{CC} or GND	6			8		80		160	m <i>P</i>	
ICT T	YPES					·	-					
/ _{IH}	High level input voltage		4.5 to 5.5	2			2		2		V	
/ _{IL}	Low level input voltage		4.5 to 5.5			0.8		0.8		0.8	V	
,	High level output voltage CMOS loads	I _{OH} = – 20 μA	4.5	4.4			4.4		4.4		.,	
′он	High level output voltage TTL loads	I _{OH} = – 4 mA	4.5	3.98			3.84		3.7		V	
/	Low level output voltage CMOS loads	I _{OL} = 20 μA	4.5			0.1		0.1		0.1	V	
OL.	Low level output voltage TTL loads	I _{OL} = 4 mA	4.5			0.26		0.33		0.4		
I	Input leakage current	V _I = V _{CC} or GND	5.5			±0.1		±1		±1	μΑ	
СС	Quiescent device current	V _I = V _{CC} or GND	5.5			8		80		160	μΑ	



5.4 Electrical Characteristics (continued)

PARAMETER		TEST	V (\(\)	25°C			–40℃ to 85℃		–55℃ to 125℃		UNIT
		CONDITIONS ⁽²⁾	V _{CC} (V)	MIN	TYP	MAX	MIN M	ΑX	MIN	MAX	ONIT
	CLR input held at V _{CC} –2.1	4.5 to 5.5		100	540	6	675		735	μΑ	
ΔI _{CC} (1)	Additional quiescent device current per input pin	Data inputs held at V _{CC} –2.1	4.5 to 5.5		100	144	1	80		196	μΑ
Input pin		CLK inputs held at V _{CC} –2.1	4.5 to 5.5		100	540	6	375		735	μΑ

- (1) For dual-supply systems theoretical worst case (V_I = 2.4 V, V_{CC} = 5.5 V) specification is 1.8mA. (2) V_I = V_{IH} or V_{IL} , unless otherwise noted.

5.5 Prerequisite for Switching Characteristics

See Parameter Measurement Information

	PARAMETER	V 00		25℃		–40℃ to	85℃	–55℃ to 1	25℃	UNIT
	PARAMETER	V _{CC} (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNII
HC TY	PES									
		2	6			5		4		
f _{MAX}	Maximum clock frequency	4.5	30			25		20		MHz
		6	35			29		23		
		2	60			75		90		
t _W	CLR pulse width	4.5	12			15		18		ns
		6	10			13		15		
		2	80			100		120		
t _W	Clock pulse width	4.5	16			20		24		ns
		6	14			17		20		
		2	60			75		70		
t _{SU}	Set-up time data to clock	4.5	12			15		18		ns
		6	10			13		15		
		2	3			3		3		
t _H	Hold time, data to clock	4.5	3			3		3		ns
		6	3			3		3		
		2	50			65		75		
t _{REM}	Removal time, $\overline{\text{CLR}}$ to clock	4.5	10			13		15		ns
		6	9			11		13		
HCT T	YPES									
f _{MAX}	Maximum clock frequency	4.5	25			20		16		MHz
t _w	CLR pulse width	4.5	12			15		18		ns
t _w	Clock pulse width	4.5	20			25		30		ns
t _{SU}	Set-up time data to clock	4.5	12			15		18		ns
t _H	Hold time, data to clock	4.5	3			3		3		ns
t _{REM}	Removal time, CLR to clock	4.5	10			13		15		ns



5.6 Switching Characteristics

Input t_r, t_f = 6 ns (See Parameter Measurement Information)

	PARAMETER	TEST	V 00	25℃		–40℃ to 85℃	-55℃ to 125℃	UNIT
	PARAMETER	CONDITIONS	V _{CC} (V)	TYP	MAX	MAX	MAX	UNIT
HC TYPE	S							
			2		150	190	225	
	Propagation delay	C _L = 50 pF	4.5		30	38	45	
t _{PLH} , t _{PHL}	Clock to output		6		26	30	38	ns
		C _L = 15 pF	5	12				
			2		150	190	225	
t _{PHL}	Propagation delay CLR to output	C _L = 50 pF	4.5		30	38	45	ns
	CEN to output		6		26	30	38	
	Output transition time		2		75	95	110	
t_{TLH},t_{THL}		C _L = 50 pF	4.5		15	19	22	ns
			6		13	16	19	
C _{IN}	Input capacitance				10	10	10	pF
f _{MAX}	Maximum clock frequency	C _L = 15 pF	5	60				MHz
C _{PD}	Power dissipation capacitance ⁽¹⁾ (2)		5	25				pF
HCT TYP	ES						1	
	Propagation delay,	C _L = 50 pF	4.5		30	38	45	
t _{PLH} , t _{PHL}	Clock to output	C _L = 15 pF	5	12				ns
t _{PHL}	Propagation delay, CLR to output	C _L = 50 pF	4.5		32	40	48	ns
t _{TLH} , t _{THL}	Output transition time	C _L = 50 pF	4.5		15	19	22	ns
C _{IN}	Input capacitance				10	10	10	pF
f _{MAX}	Maximum clock frequency	C _L = 15 pF	5	50				MHz
C _{PD}	Power dissipation capacitance ⁽¹⁾ (2)		5	25				pF

 C_{PD} is used to determine the dynamic power consumption, per flip-flop. $P_D = C_{PD} \, V_{CC} \, ^2 \, f_i + \Sigma \, (C_L \, V_{CC} \, ^2 + f_O)$ where f_i = input frequency, f_O = output frequency, C_L = output load capacitance, V_{CC} = supply voltage.



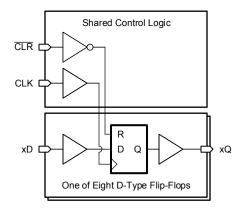
6 Detailed Description

6.1 Overview

The 'HC273 and 'HCT273 high speed octal D-Type flip-flops with a direct clear input are manufactured with silicon-gate CMOS technology. They possess the low power consumption of standard CMOS integrated circuits.

Information at the D input is transferred to the Q outputs on the positive-going edge of the clock pulse. All eight flip-flops are controlled by a common clock (CLK) and a common reset (CLR). Resetting is accomplished by a low voltage level independent of the clock. All eight Q outputs are reset to a logic 0.

6.2 Functional Block Diagram



6.3 Device Functional Modes

Table 6-1. Truth Table⁽¹⁾

	INPUTS									
RESET (CLR)	CLOCK CLK	DATA D _n	Q							
L	X	Х	L							
Н	1	Н	Н							
Н	1	L	L							
Н	L	Х	Q ₀							

(1) H = high voltage level, L = low voltage level, X = don't care, ↑ = transition from low to high level, Q0 = level before the indicated steady-state input conditions were established

 V_{CC}

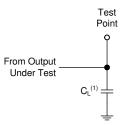


7 Parameter Measurement Information

Phase relationships between waveforms were chosen arbitrarily. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, Z_O = 50 Ω , t_t < 6 ns.

For clock inputs, f_{max} is measured when the input duty cycle is 50%.

The outputs are measured one at a time with one input transition per measurement.



(1) C_L includes probe and test-fixture capacitance.

Figure 7-1. Load Circuit for Push-Pull Outputs

Clock

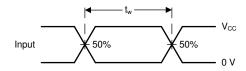
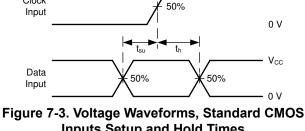
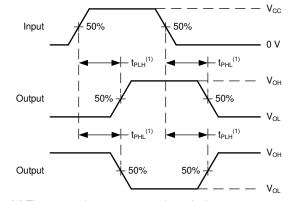


Figure 7-2. Voltage Waveforms, Standard CMOS Inputs Pulse Duration

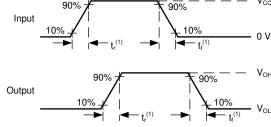


Inputs Setup and Hold Times



(1) The greater between t_{PLH} and t_{PHL} is the same as t_{pd} .

Figure 7-4. Voltage Waveforms, Propagation Delays for Standard CMOS Inputs



(1) The greater between t_r and t_f is the same as t_t .

Figure 7-5. Voltage Waveforms, Input and Output Transition Times for Standard CMOS Inputs



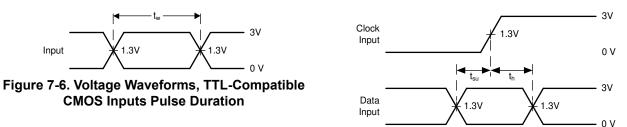
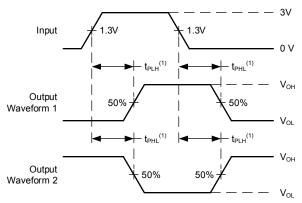


Figure 7-7. Voltage Waveforms, TTL-Compatible CMOS Inputs Setup and Hold Times



(1) The greater between t_{PLH} and t_{PHL} is the same as $t_{\text{pd}}.$

Figure 7-8. Voltage Waveforms, Propagation Delays for TTL-Compatible Inputs



8 Power Supply Recommendations

The power supply can be any voltage between the minimum and maximum supply voltage rating located in the Recommended Operating Conditions. Each V_{CC} terminal should have a good bypass capacitor to prevent power disturbance. A 0.1-µF capacitor is recommended for this device. It is acceptable to parallel multiple bypass caps to reject different frequencies of noise. The 0.1-µF and 1-µF capacitors are commonly used in parallel. The bypass capacitor should be installed as close to the power terminal as possible for best results.

9 Layout

9.1 Layout Guidelines

When using multiple-input and multiple-channel logic devices inputs must not ever be left floating. In many cases, functions or parts of functions of digital logic devices are unused; for example, when only two inputs of a triple-input AND gate are used or only 3 of the 4 buffer gates are used. Such unused input pins must not be left unconnected because the undefined voltages at the outside connections result in undefined operational states. All unused inputs of digital logic devices must be connected to a logic high or logic low voltage, as defined by the input voltage specifications, to prevent them from floating. The logic level that must be applied to any particular unused input depends on the function of the device. Generally, the inputs are tied to GND or V_{CC}, whichever makes more sense for the logic function or is more convenient.



10 Device and Documentation Support

TI offers an extensive line of development tools. Tools and software to evaluate the performance of the device, generate code, and develop solutions are listed below.

10.1 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Subscribe to updates* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

10.2 Support Resources

TI E2E[™] support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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10.3 Trademarks

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10.4 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

10.5 Glossary

TI Glossary

This glossary lists and explains terms, acronyms, and definitions.

11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.



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PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead finish/ Ball material	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
5962-8772501RA	ACTIVE	CDIP	J	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-8772501RA CD54HCT273F3A	Samples
CD54HC273F	ACTIVE	CDIP	J	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD54HC273F	Samples
CD54HC273F3A	ACTIVE	CDIP	J	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	8409901RA CD54HC273F3A	Samples
CD54HCT273F	ACTIVE	CDIP	J	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	CD54HCT273F	Samples
CD54HCT273F3A	ACTIVE	CDIP	J	20	1	Non-RoHS & Green	SNPB	N / A for Pkg Type	-55 to 125	5962-8772501RA CD54HCT273F3A	Samples
CD74HC273E	ACTIVE	PDIP	N	20	20	RoHS & Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC273E	Samples
CD74HC273M96	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC273M	Samples
CD74HC273M96E4	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC273M	Samples
CD74HCT273E	ACTIVE	PDIP	N	20	20	RoHS & Non-Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT273E	Samples
CD74HCT273EE4	ACTIVE	PDIP	N	20	20	RoHS & Non-Green	NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT273E	Samples
CD74HCT273M96	ACTIVE	SOIC	DW	20	2000	RoHS & Green	NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT273M	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

PACKAGE OPTION ADDENDUM

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- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF CD54HC273, CD54HCT273, CD74HC273, CD74HCT273:

Catalog: CD74HC273, CD74HCT273

Military: CD54HC273, CD54HCT273

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Military QML certified for Military and Defense Applications

PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
CD74HC273M96	SOIC	DW	20	2000	330.0	24.4	10.9	13.3	2.7	12.0	24.0	Q1
CD74HC273M96	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
CD74HCT273M96	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1
CD74HCT273M96	SOIC	DW	20	2000	330.0	24.4	10.9	13.3	2.7	12.0	24.0	Q1



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*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74HC273M96	SOIC	DW	20	2000	367.0	367.0	45.0
CD74HC273M96	SOIC	DW	20	2000	367.0	367.0	45.0
CD74HCT273M96	SOIC	DW	20	2000	367.0	367.0	45.0
CD74HCT273M96	SOIC	DW	20	2000	356.0	356.0	41.0

PACKAGE MATERIALS INFORMATION

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TUBE



*All dimensions are nominal

Device	Package Name	Package Type	Pins	SPQ	L (mm)	W (mm)	T (µm)	B (mm)
CD74HC273E	N	PDIP	20	20	506	13.97	11230	4.32
CD74HCT273E	N	PDIP	20	20	506	13.97	11230	4.32
CD74HCT273EE4	N	PDIP	20	20	506	13.97	11230	4.32

14 LEADS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOIC



NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

 2. This drawing is subject to change without notice.

 3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



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